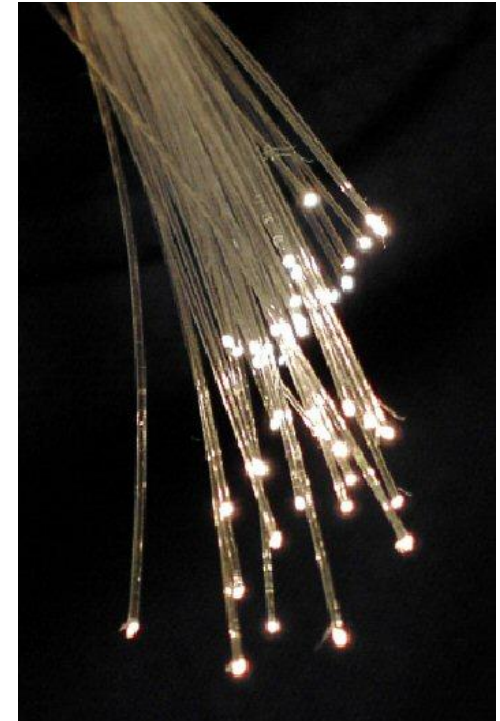
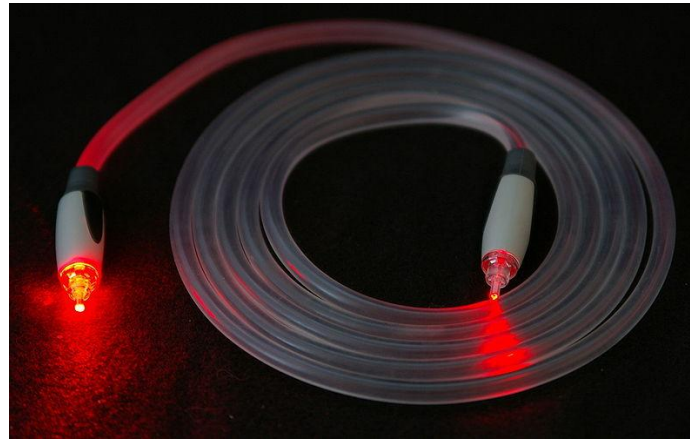


Sensores Ópticos

Medição de luz

Geração de luz



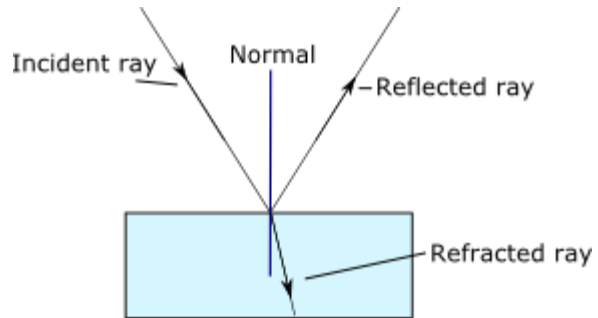
O que é luz???



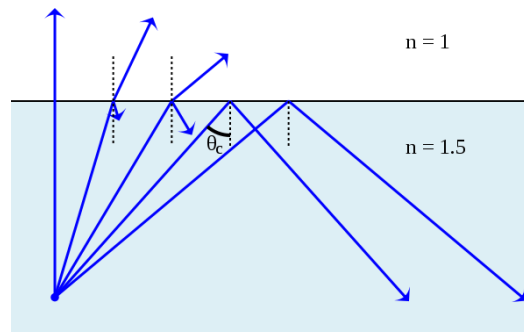
Raio
Onda
Partícula

Raios

Propagação retilínea

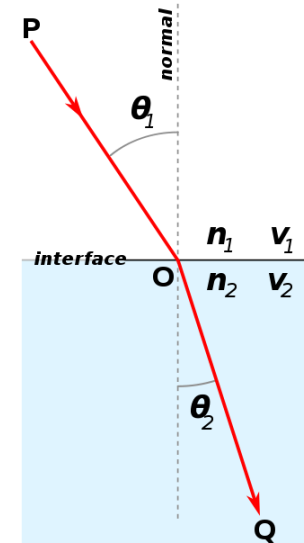


Reflexão total



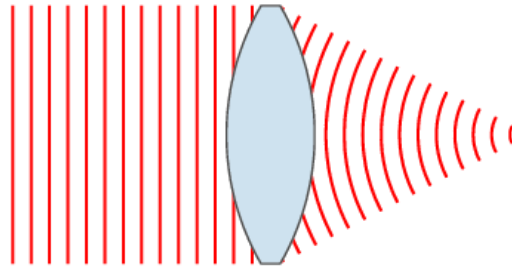
Lei de Snell

$$\frac{\sin \theta_1}{\sin \theta_2} = \frac{v_1}{v_2} = \frac{n_2}{n_1}$$

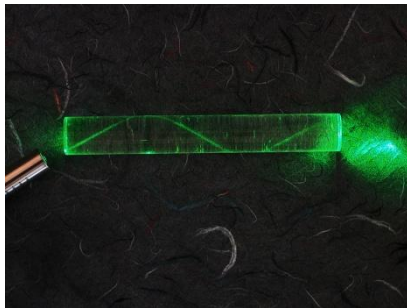


Raios

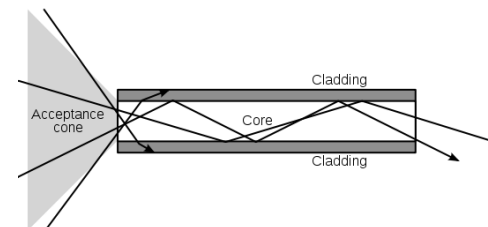
Focalização e colimação



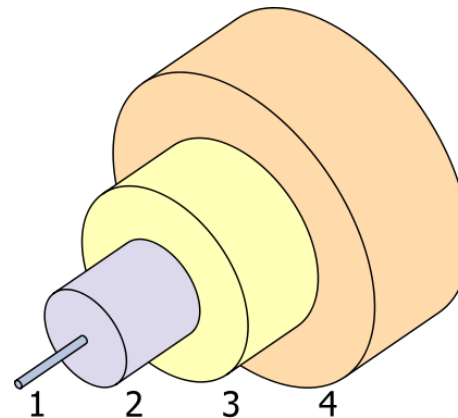
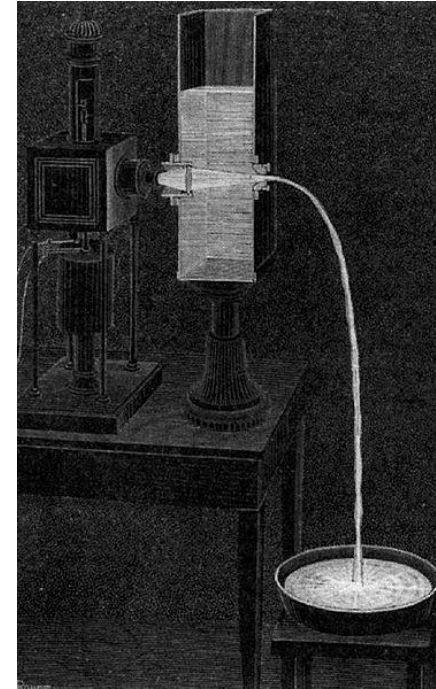
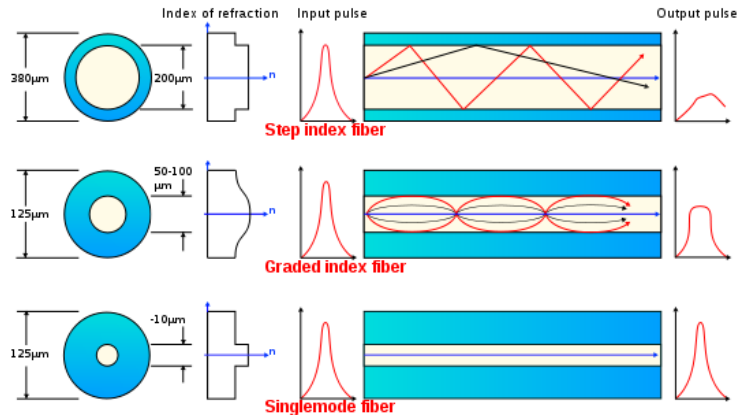
Confinamento de luz



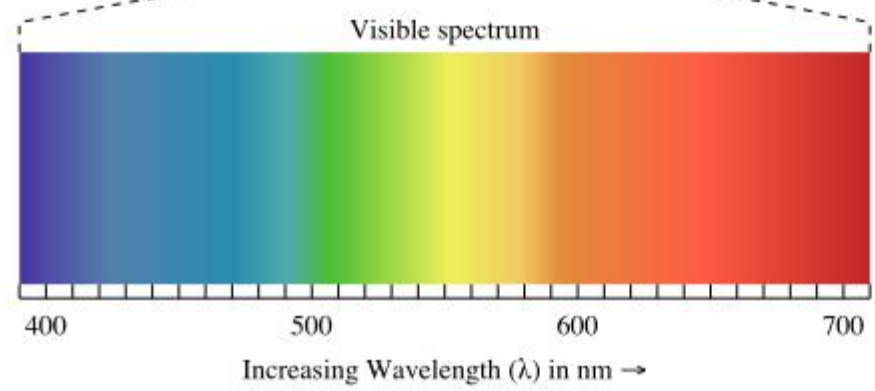
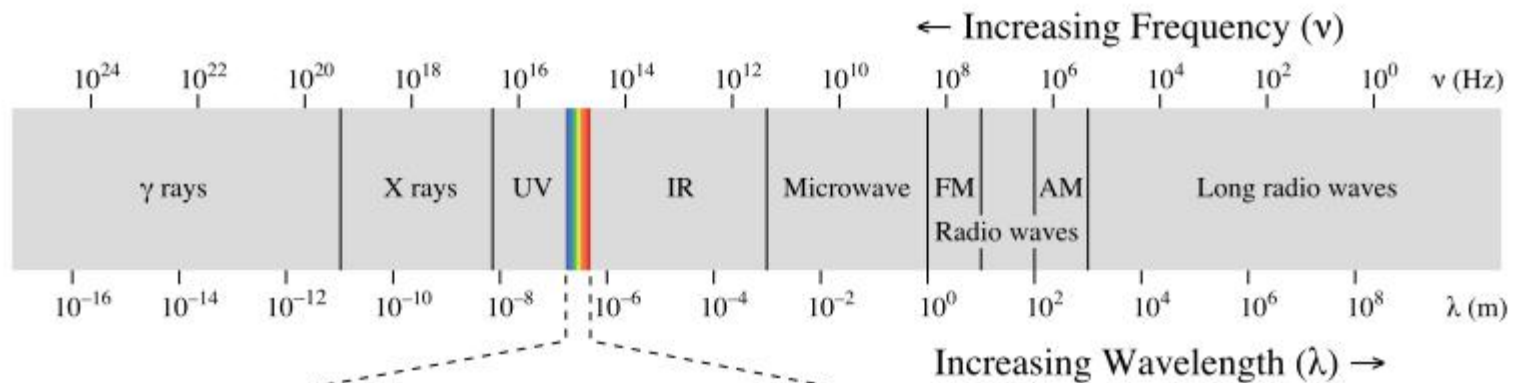
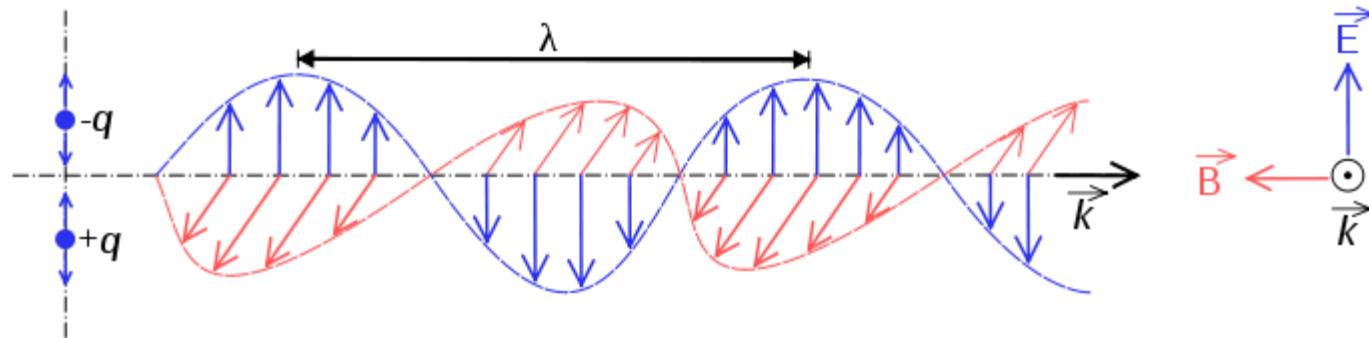
Fibra óptica



Fibra óptica

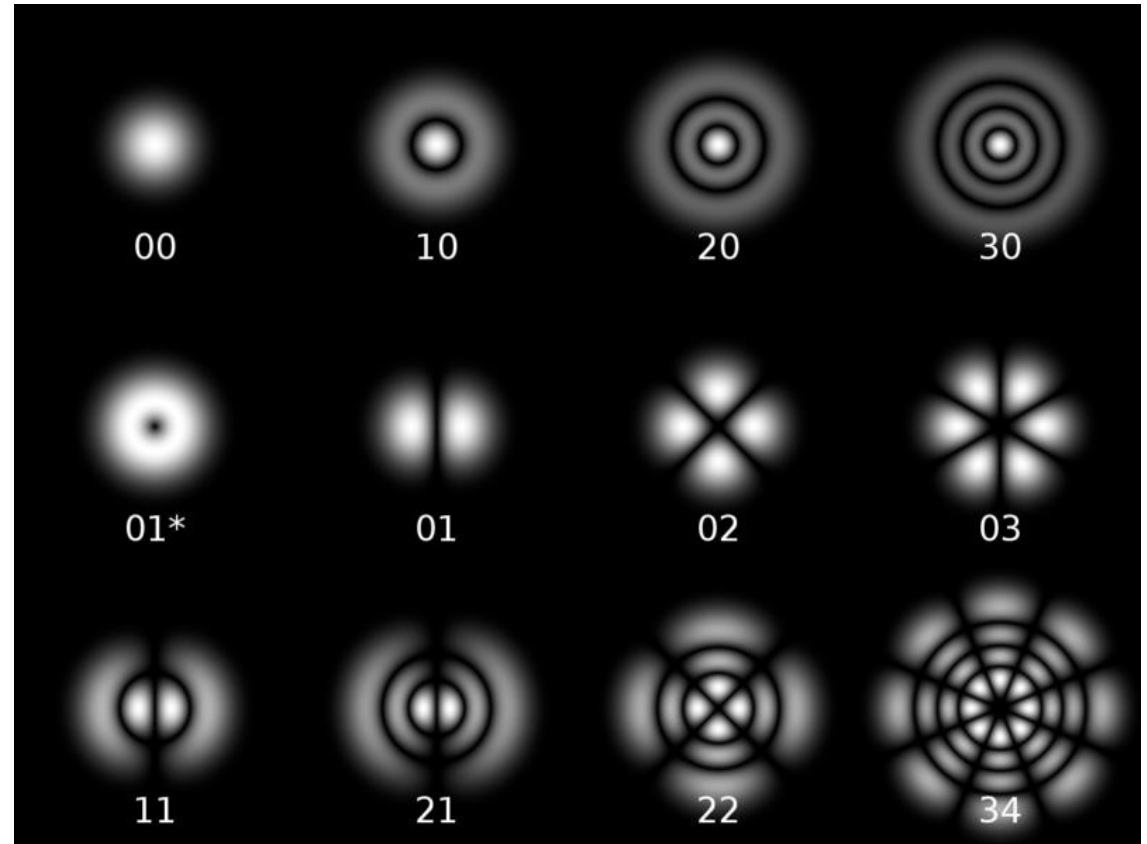
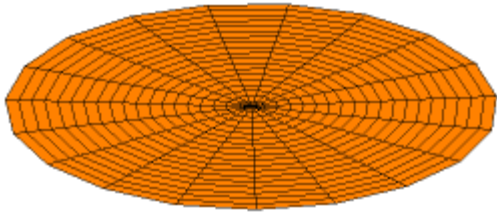


Onda

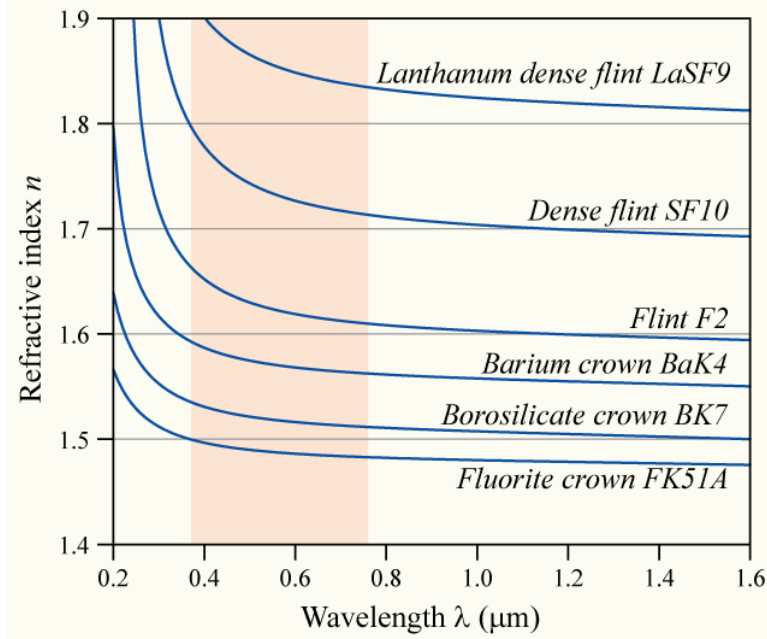


Onda

Modos transversais



Lei de Snell

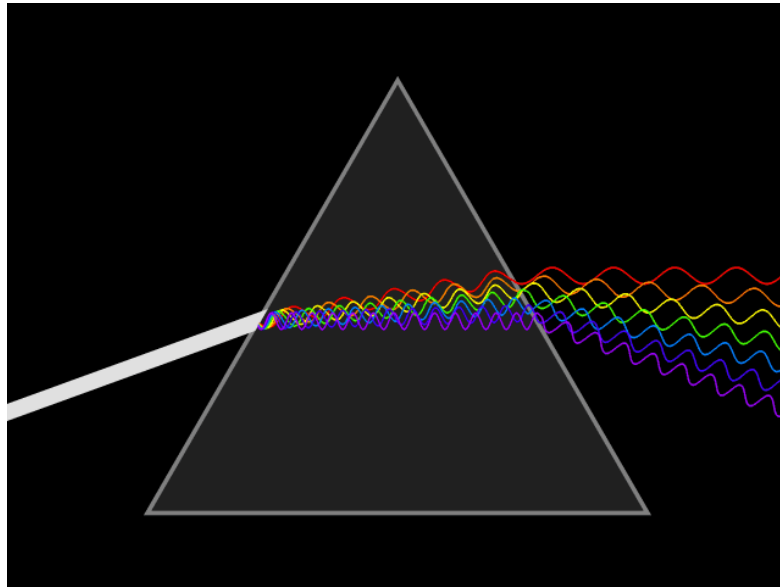


Equação de Sellmeier

$$n^2(\lambda) = A + \frac{B_1\lambda^2}{\lambda^2 - C_1} + \frac{B_2\lambda^2}{\lambda^2 - C_2}$$

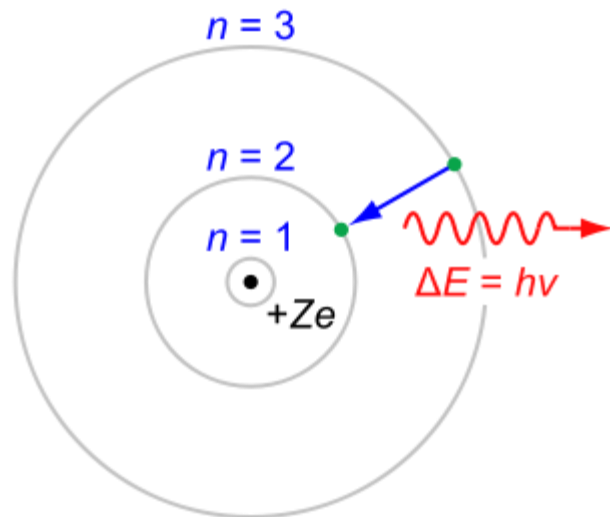
Dispersão

Aberração cromática

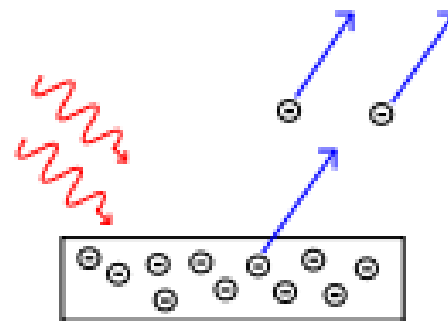


TESTE

Partícula

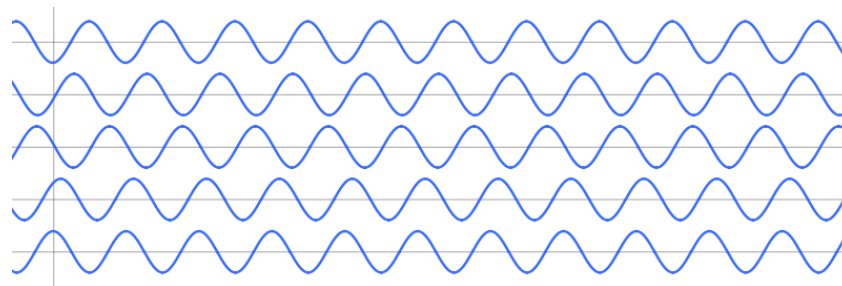
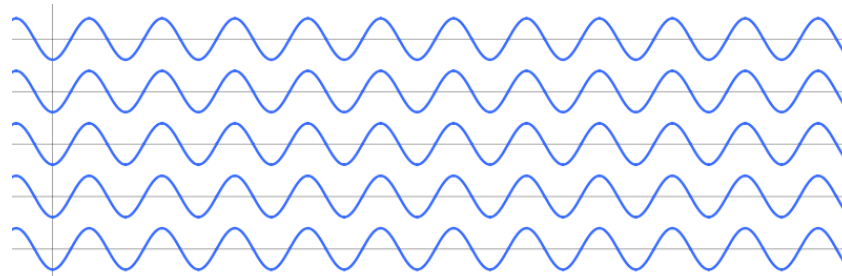
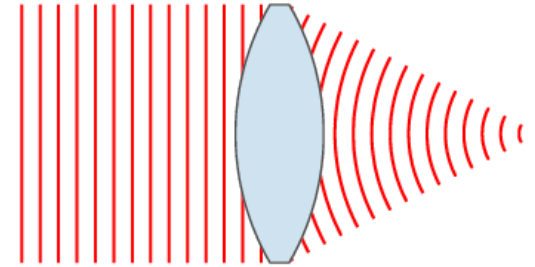
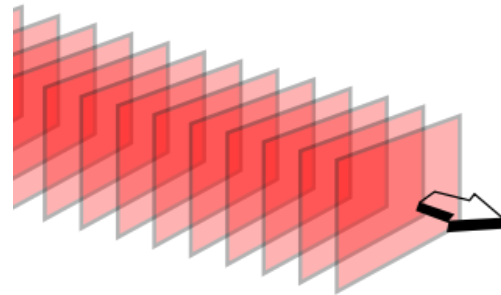


$$E = hf = \frac{hc}{\lambda}$$



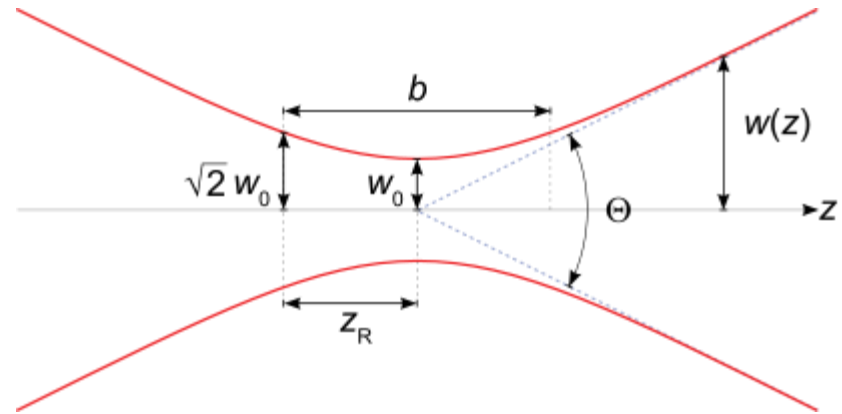
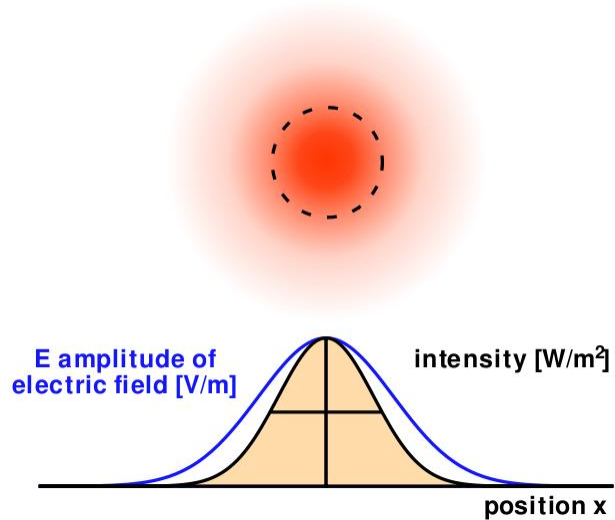
Onda

Frente de onda



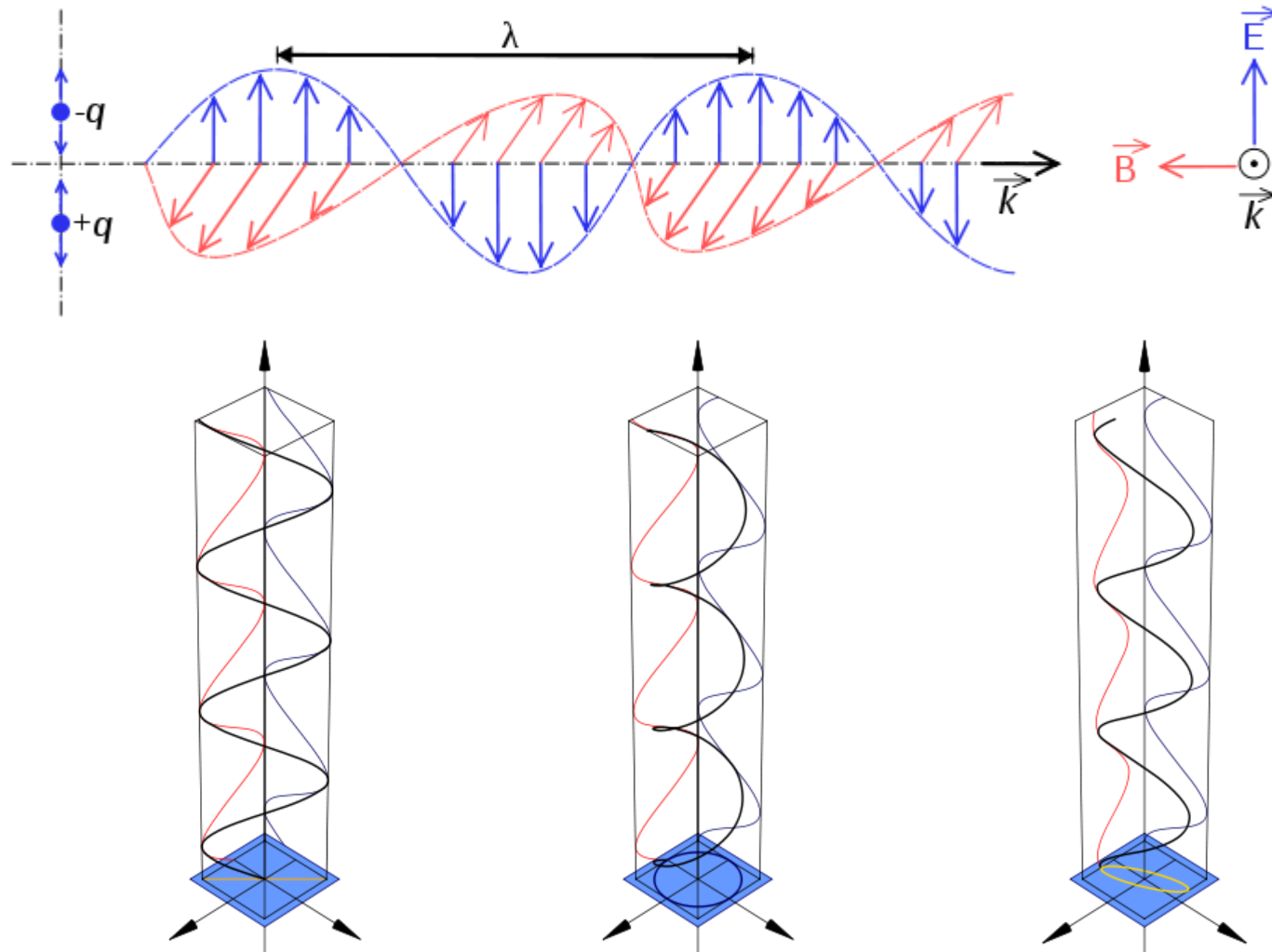
Onda

Feixe Gaussiano

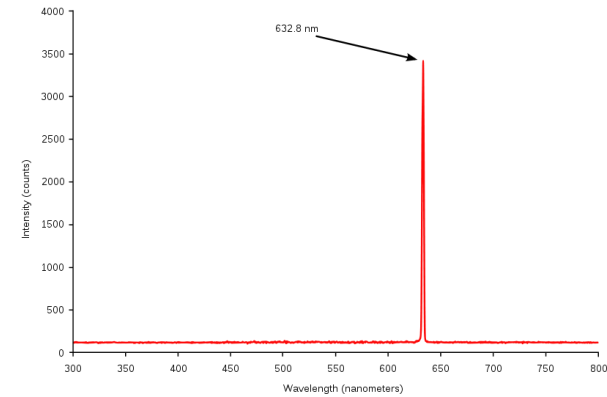
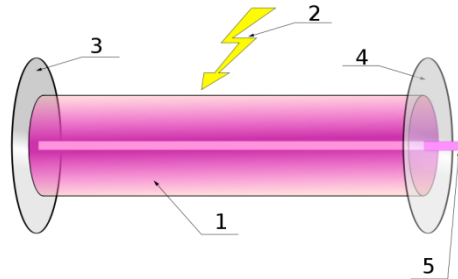


$$I(r, z) = \frac{|E(r, z)|^2}{2\eta} = I_0 \left(\frac{w_0}{w(z)} \right)^2 \exp \left(\frac{-2r^2}{w^2(z)} \right),$$

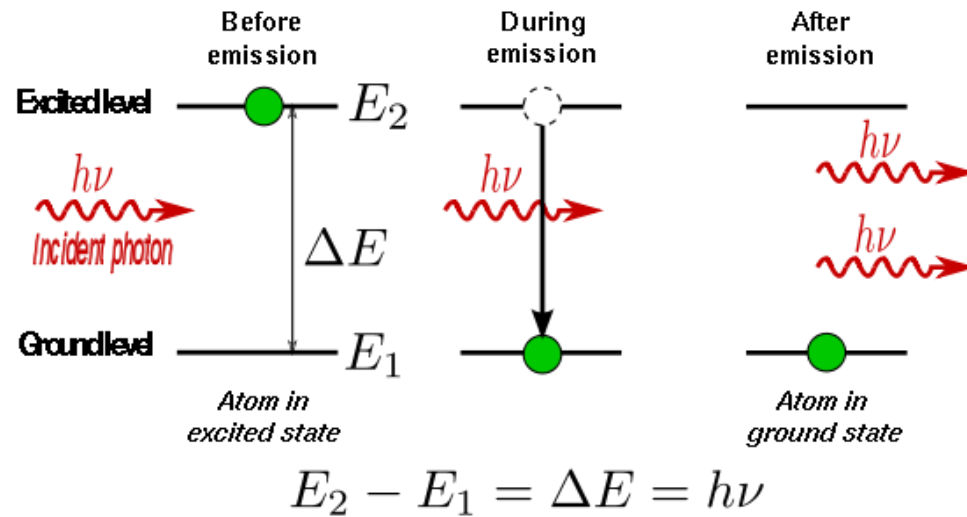
Polarização



Laser



Emissão espontânea X Emissão estimulada



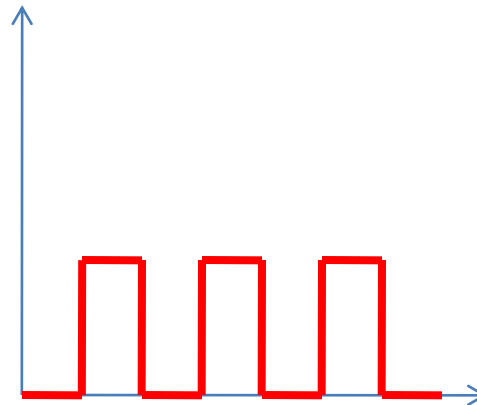
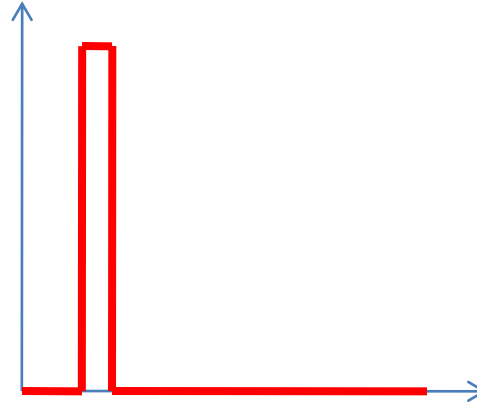
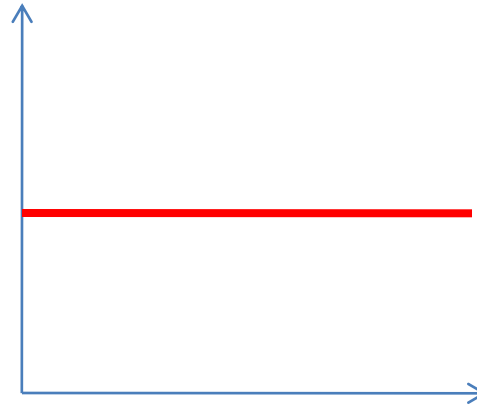
Laser

Modos de operação

CW

Pulsado – Acúmulo de energia

Chaveado – AM



Sensores Ópticos

Iluminância – fluxo luminoso/área de uma superfície (lux)

Fluxo luminoso – potência de radiação emitida por
uma fonte luminosa (lúmen)

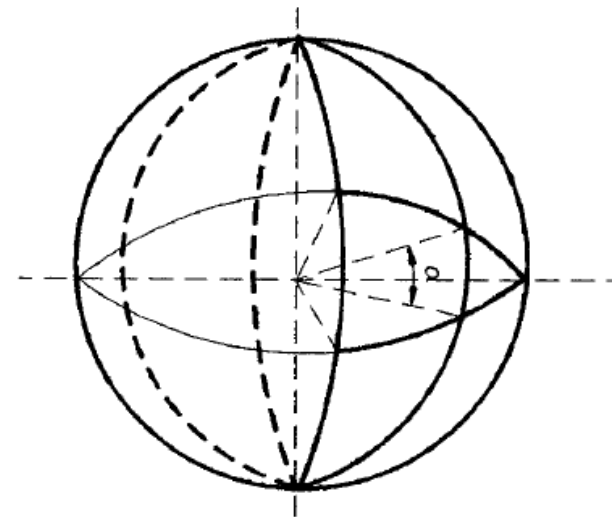
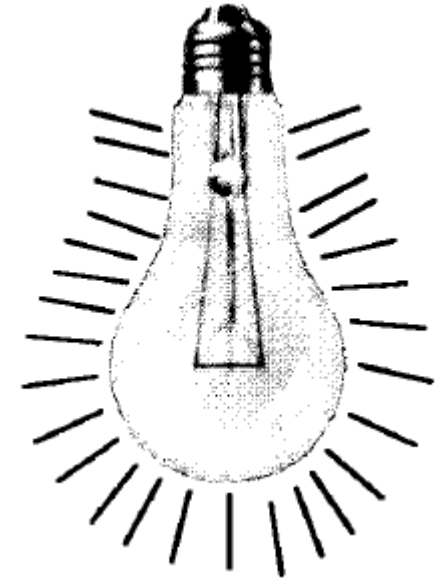
Eficiência luminosa – fluxo luminoso/potência consumida
(lúmens/W)

Intensidade luminosa – fluxo luminoso/ângulo sólido
(candela – cd)

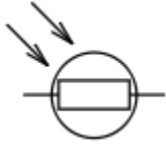
Luminância – Intensidade luminosa/superfície iluminada
(cd/m²)

Reflectância

Emitância (lúmens/m²)



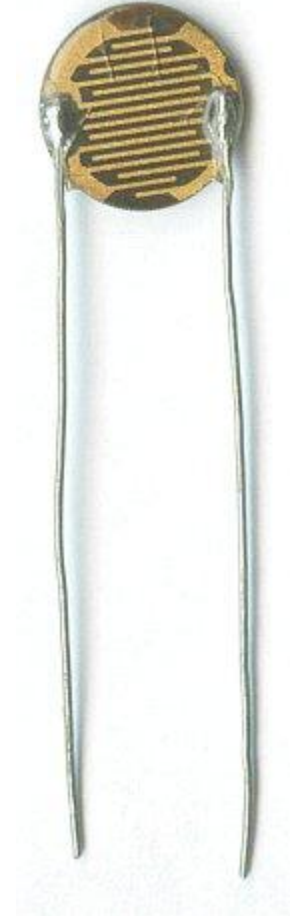
LDR



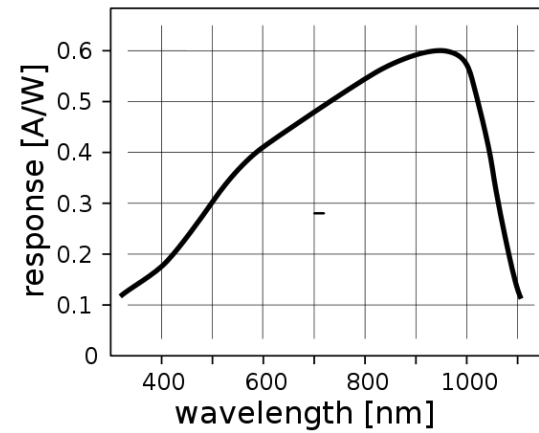
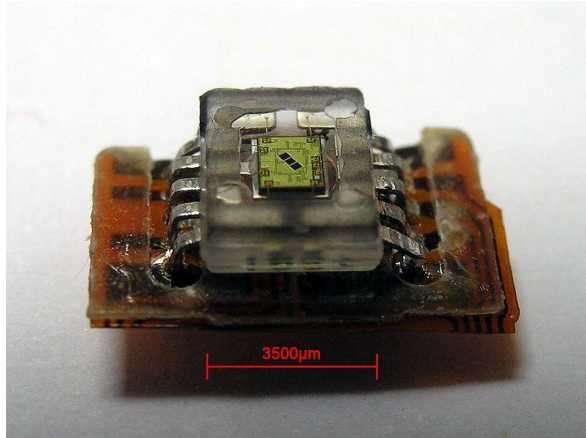
Material semicondutor

Variação de resistência com luz

Tempo de resposta de dezenas de ms (desvantagem???)



Fotodiodo



Modo fotovoltaico
Modo fotocondutivo

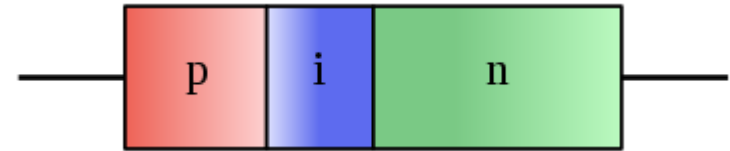
Fotodiodo

Características construtivas

Tipo PN – fotodiodo x fototransistor

Tipo PIN

Tipo avalanche (APD)



Sensibilidade (Responsivity) – A/W, A/lm

Corrente de escuro (Dark current)

Potência equivalente de ruído (Noise-equivalente power)

Resposta em frequência – capacitância da junção

Fotodiodo

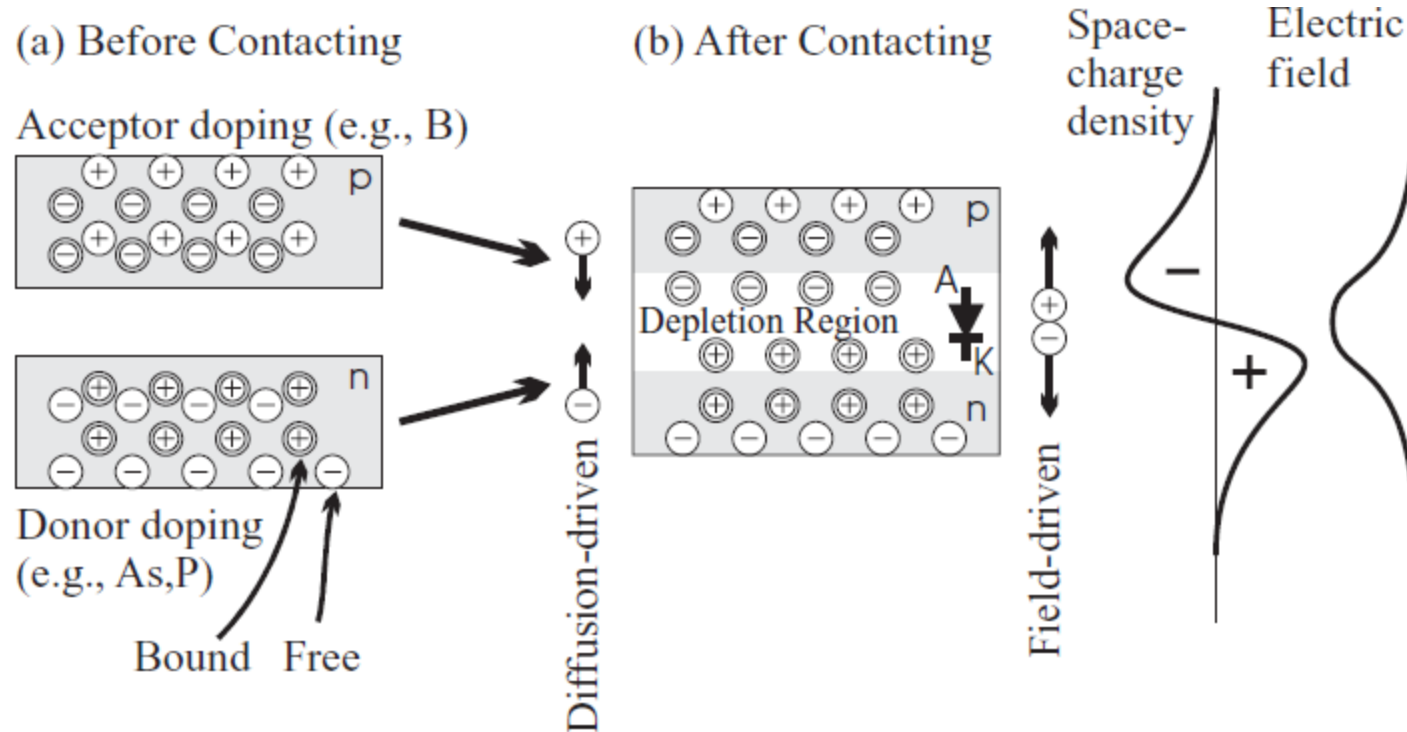


Figure 1.1 The pn-junction. The presence of predominately different polarities of free carriers in the two contacted materials leads to asymmetrical conductivity, a rectifying action. Bound charges are indicated by a double circle and free charges by a single circle.

Fotodiodo

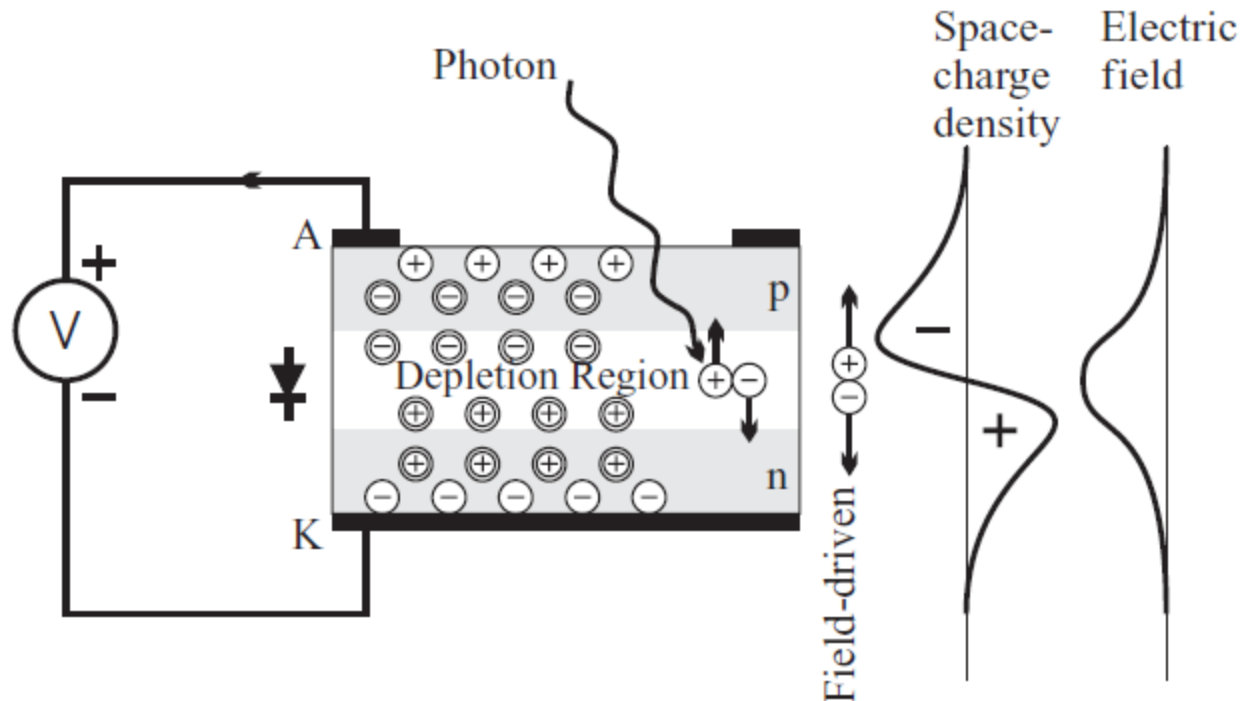


Figure 1.2 When a photon with energy greater than the material bandgap forms a hole-electron pair, a terminal voltage will be generated, positive at the p-type anode.

Fotodiodo

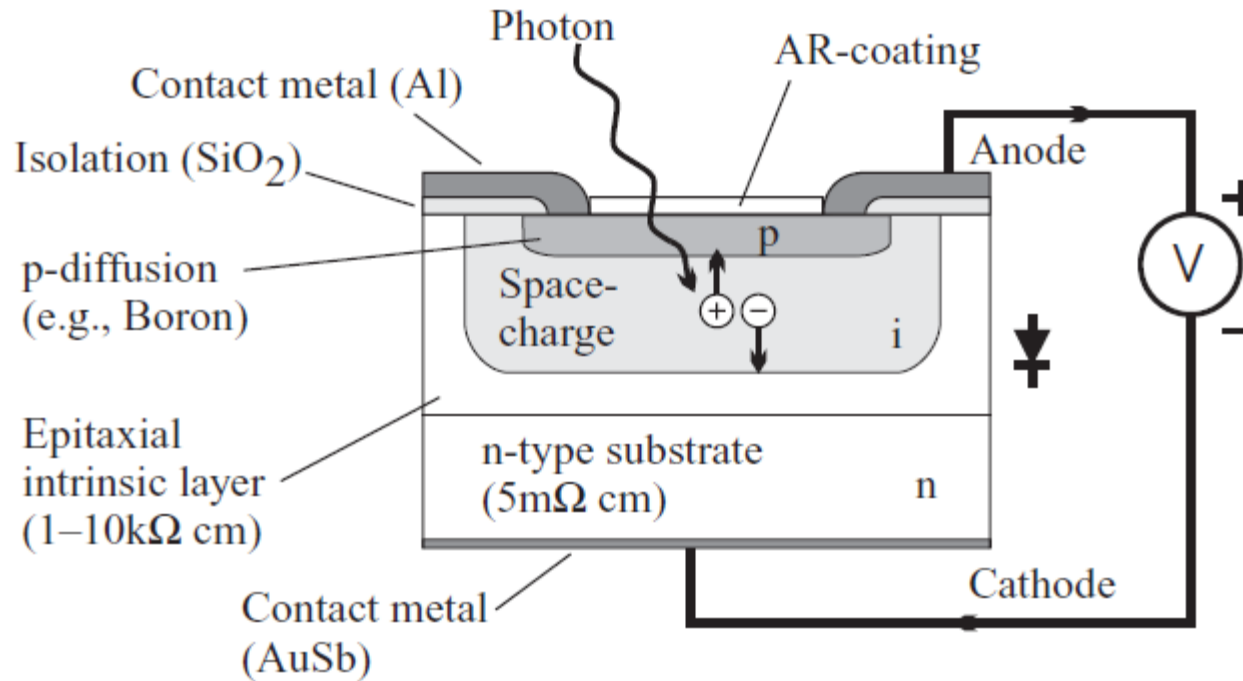


Figure 1.4 Most photodiodes are formed by diffusing dopants into epitaxially formed layers. The use of a low conductivity intrinsic layer leads to thickening of the space-charge region, lower capacitance, and improved sensitivity.

Fotodiodo

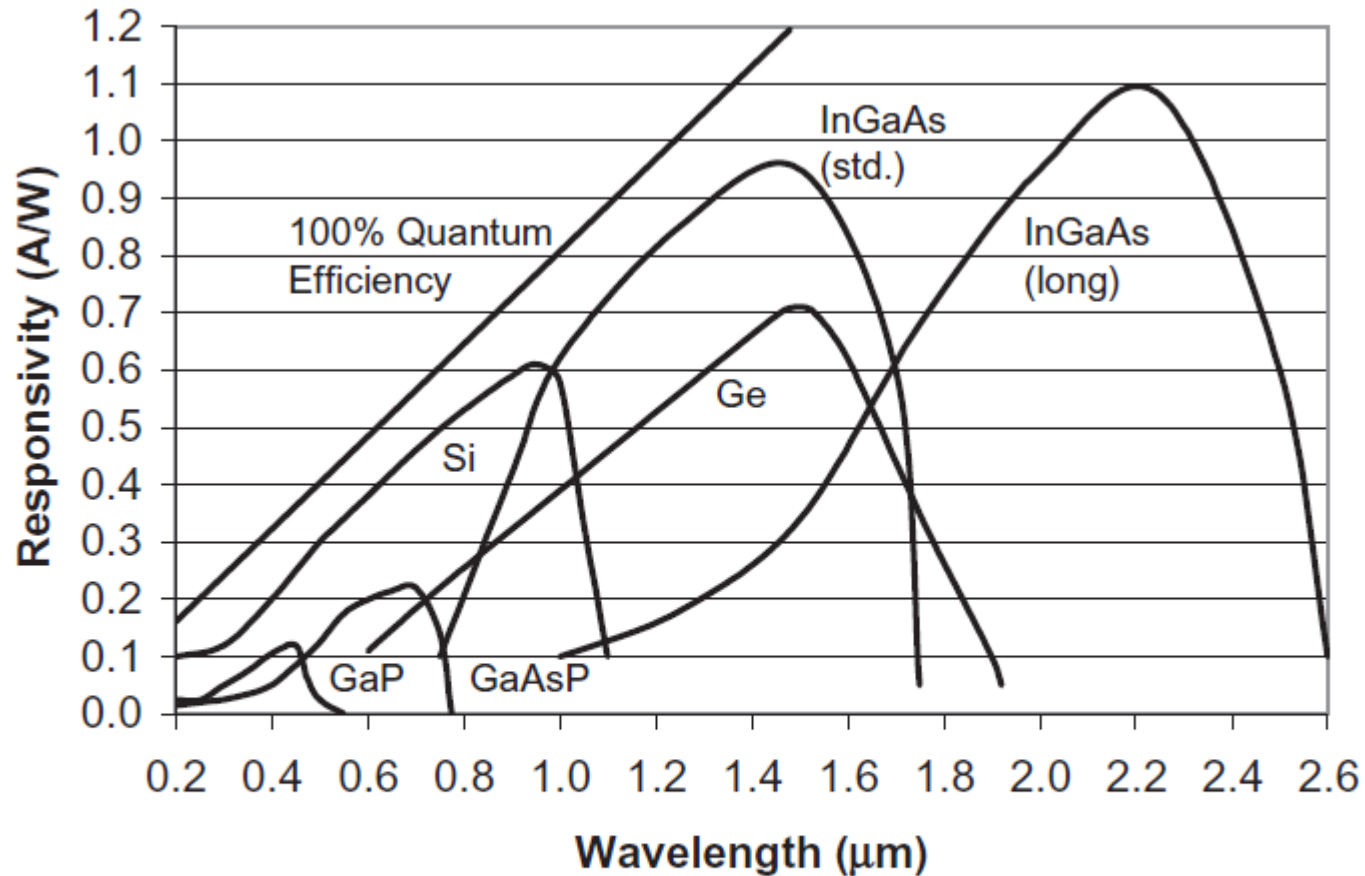


Figure 1.5 Photodiodes of different semiconductor materials show sensitivity in different wavelength regions, limited at long wavelength by their energy gap. 100 percent quantum efficiency means that one photon produces one hole-electron pair.

Fotodiodo

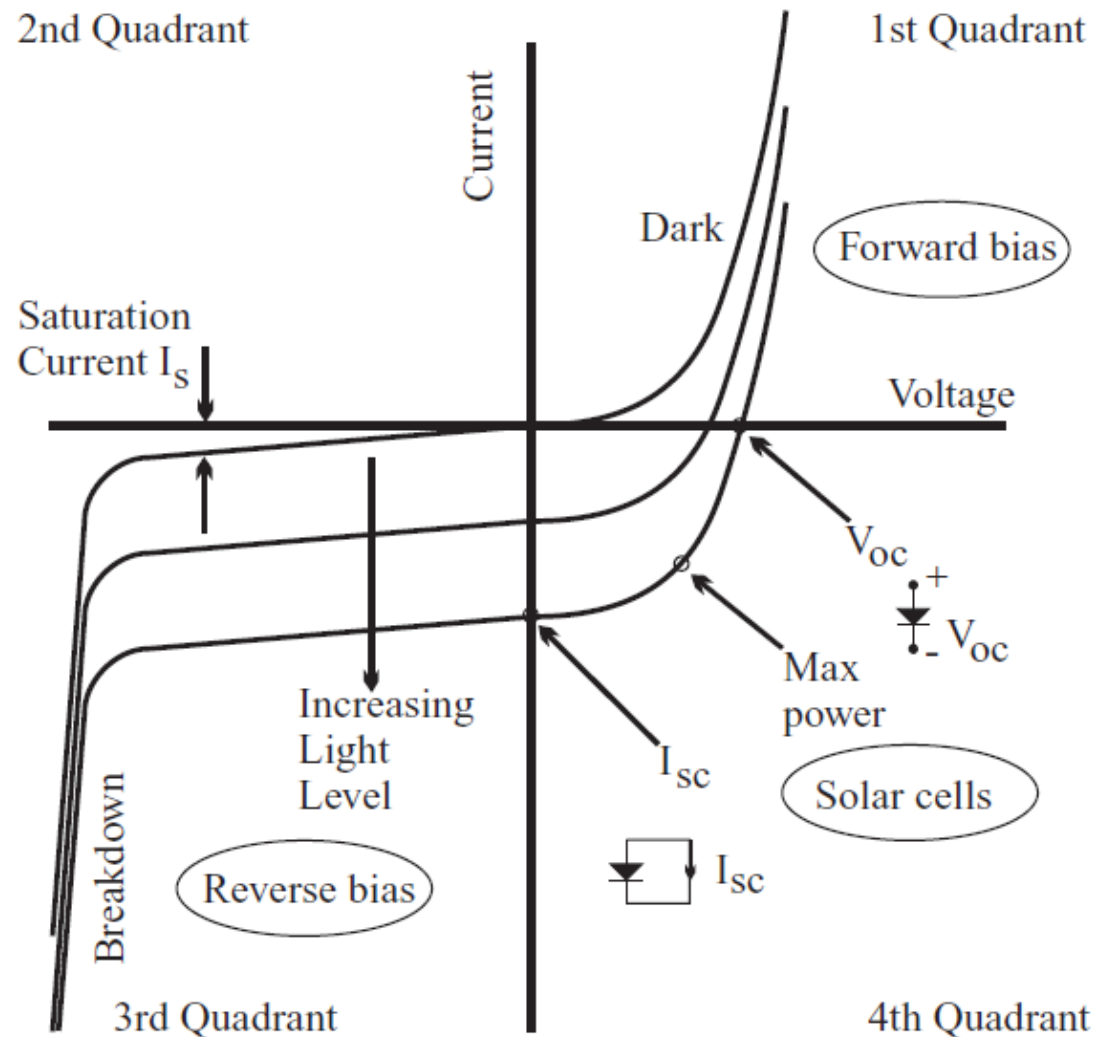
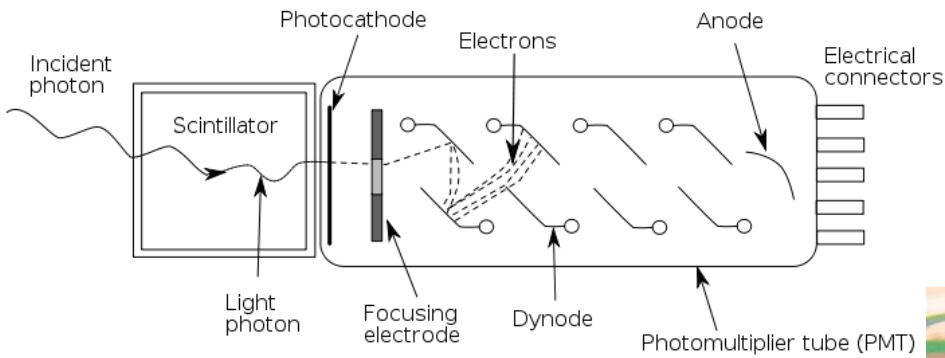


Figure 1.9 Four-quadrant current/voltage characteristic. Without illumination this is similar to a conventional diode. Increasing illumination shifts the characteristic in the negative current direction. Detection is possible in quadrants 1, 3, and 4.

Fotodiodo

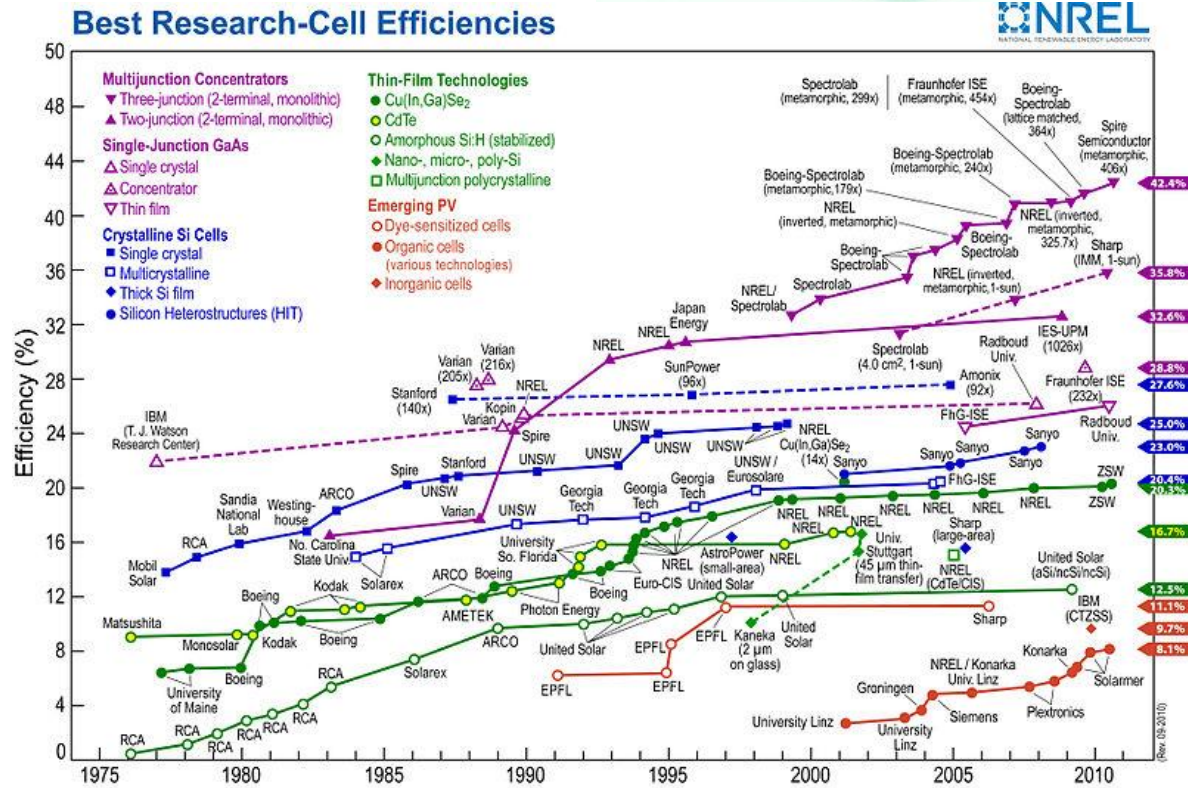
Fotomultiplicador



Ausência de ruído Johnson



Células fotovoltaicas



CCD x CMOS

Ruído, escalabilidade, estabilidade temporal

